December 12, 2003

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572 28 Davis Avenue Poughkeepsie, N.Y. 12603

Subject:

Serial No. 10/664,210 09/17/03

Yong Meng Lee et al.

METHOD OF FORMING DOUBLE-GATE SEMICONDUCTOR-ON-INSULATOR (SOI) TRANSISTORS

INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation In An Application.

The following Patents and/or Publications are submitted to comply with the duty of disclosure under CFR 1.97-1.99 and 37 CFR 1.56.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on December 19, 2003.

Stephen B. Ackerman Reg.# 37761

Signature/Date

CS-01-208

- U.S. Patent 6,451,656 to Yu et al., "CMOS Inverter Configured From Double Gate MOSFET and Method of Fabricating Same," describes a double-gate transistor on semiconductor-oninsulator (SOI).
- U.S. Patent 6,413,802 to Hu et al., "FinFET Transistor Structures Having a Double Gate Channel Extending Vertically From a Substrate and Methods of Manufacture," describes a double-gate FinFET on semiconductor-on-insulator (SOI).
- U.S. Patent 6,365,465 to Chan et al., "Self-Aligned Double-Gate MOSFET by Selective Epitaxy and Silicon Wafer Bonding Techniques," describes a process for a double gate MOSFET on semiconductor-on insulator (SOI).
- U.S. Patent 6,396,108 to Krivokapic et al., "Self-Aligned Double Gate Silicon-On-Insulator (SOI) Device," describes a process for a double gate MOSFET on semiconductor-on-insulator (SOI).

Sincerely

Stephen B. Ackerman,

Reg. No. 37761

orm PIO-1			ЛN	ומ	ISC	21 (OSURE C	HOITATION	CS-01-208			10/664	4,210	<u>) ·</u>
OI PINE S	\	IN	AN	A	PF	PLI	CATION	·	Applicant Young	M.	ng L	ee et		· · · · · · · · · · · · · · · · · · ·
NE 2 2 2003		יטנ ט	०१ व	sho	ols i	ilna	cossary)		14ng Dam 09/1-	1/03	3 6	roup Art Unit		
	3/							U. S. PATE	NT DOCUMEN	ıts				
TRADE THE	DOCUMENT HOMBER					R	DATE HAVE		KUME		CLASS	MECTAR	Y APP	DATE
	6	4	1	6	2	6	9/17/02	Yuet	alı		438	283	2/2	8/01
	6	4	3	5	३ ०	2	7/2/02				438	151	10/23/00	
	6	3 (25	4	6	5	4/2/02	Chan	et al.		438	283	3/19	1/99
	6	30	16		0	8	5/28/02	Krivak	apic et	al.	257	365	11/13	5/00
									•				'	
													,	
,														
							·							
												,		•
								1.3						
	·							FOREIGN PA	TENT DOCUM	ENTS				
	∞	CUM	4 TK	เบม	OCF		OATE	cou	YATAY	,	CLSS	SUDCLASS	YES	Allen CM
								·	·					
,												•		
								OTHER DOC	JMENTS (Indud	ơng Aưu	or, Tive, C	alo, Portinorx	Pagas, El	c.)
														· · · · · · · · · · · · · · · · · · ·
							 		· · · · · · · · · · · · · · · · · · ·			<u></u>		·····
				<u></u>										
1	ì	1					,					, .		-
		<u> </u>									,			
1														
														·

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.